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50 W / 60 W Direct AC LED Driver Analog Dimming

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This reference design covers the specification, theory of operation, testing and construction of a design based on the NCL30170. The design demonstrates 50 W / 60 W analog dimming with accurate current regulation and low THD performance.



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REFERENCE DESIGN

Table 1.

Input Voltage	108–132 Vac	Low line ADIM
	198–264 Vac	High line ADIM
Line Frequency	50 Hz / 60 Hz	
Output Power	50 W / 60 W	Low line: 50 W High line: 60 W
Power Factor (Maximum LED Output)	0.95	Min
THD (Nominal Input Voltage)	13%	Мах
Line Regulation	±2%	
Analog Dimming Range	< 5 %	
Start Up Time	< 200 ms	Тур.
Percent Flicker	< 30%	With E-cap
Lighting Surge	CM: ±2.0 kV (Line to PE) DM: ±2.0 kV (Line to Neutral)	ANSI/IEEE C62.41-1991 Class A
EMI	Conducted	9 kHz–30 MHz

Key Features

- Accurate Constant LED Current across Input Voltage Range
- Selectable LED Channel Counts using Advanced Topology
- Excellent Power Factor and THD with Sinusoidal Current Shape
- Wide Analog dimming range < 5 %
- Excellent Phase-cut dimmer compatibility
- Protections
 - Input Over Voltage Protection
 - Thermal Shut Down
 - Sensing Resistor Short Protection

1

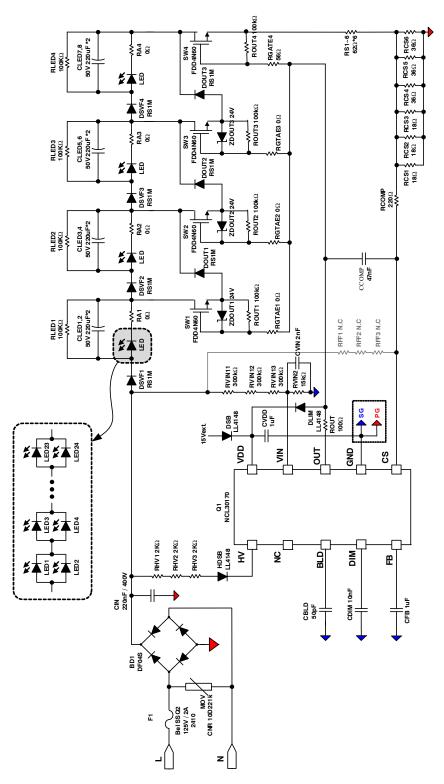


Figure 1. Schematic for Low Line 50 W ADIM

Table 2. BILL OF MATERIALS FOR LOW LINE (BOM)

Part Reference	Part Description	Q'ty	Vendor	Value
Q1	NCL30170 / IC SOIC 10	1	ON Semiconductor	NCL30170
F1	fast Acting 125 V, 2 A, SSQ2 2410	125 V, 2 A, SSQ2 2410 1 Bel fuse		
MOV	CNR10D221K 1 ANY			
RCS1, RCS2, RCS3	RES, SMD, 1/2 W, 3216	3	Yageo	18 Ω
RCS4, RCS5, RCS6	RES, SMD, 1/2 W, 3216	3	Yageo	36 Ω
RHV1, RHV2, RHV3	RES, SMD, 1/2 W, 3216	3	Yageo	2 ΚΩ
RVIN11, RVIN12	RES, SMD, 1/2 W, 3216	2	Yageo	300 KΩ
RVIN13	RES, SMD, 1/2 W, 3216	1	Yageo	220 KΩ
RVIN2	RES, SMD, 1/2 W, 3216	1	Yageo	13 KΩ
RLED1 ~ RLED4, ROUT1 ~ ROUT4	RES, SMD, 1/2 W, 3216	8	Yageo	100 KΩ
ROUT	RES, SMD, 1/2 W, 3216	1	Yageo	100 Ω
RGATE4	RES, SMD, 1/2 W, 3216	1	Yageo	56 Ω
RCOMP	RES, SMD, 1/2 W, 3216	1	Yageo	220 Ω
RS1 ~ RS6	RES, SMD, 1/2 W, 3216	6	Yageo	62 Ω
CVIN	220nF / 400 V	1		220 nF
CLED1 ~ CLED8	220 μF / 50 V	8	Samwha	220 μF
CVDD	Cap, 3216 SMD, Ceramic, 50 V, X7R	1	Kemet	1 μF
CBLD	Cap, 2012 SMD, Ceramic, 25 V, X7R	1	Kemet	50 pF
CDIM	Cap, 2012 SMD, Ceramic, 25 V, X7R	1	Kemet	10 nF
CFB	Cap, 2012 SMD, Ceramic, 25 V, X7R	1	Kemet	1 μF
CCOMP	Cap, 3216 SMD, Ceramic, 50 V, X7R	1	Kemet	47 nF
CVIN2	Cap, 3216 SMD, Ceramic, 50 V, X7R	1	Kemet	2 nF
DLIM	Diode, 100 V, 150 mA, Fast recovery	1	1 ON Semiconductor	
DSVF1 ~ DSVF4, DOUT1 ~ DOUT3	Diode, 1000 V, 1 A, Fast recovery	7	ON Semiconductor	RS1M
DSB, HDSB	Diode, 100 V, 150 mA , Fast recovery	2	2 ON Semiconductor	
ZDOUT1, ZDOUT2, ZDOUT3	ZENER Diode 24 V	3 ON Semiconductor		24 V
BD1	Bridge Diode 400 V, 1 A	1 ON Semiconductor		DF04S
LED1 ~ LED96	MP-3030-1100-30-80	96 LUMINUS		3 V / 240 m/
SW1, SW2, SW3, SW4	MOSFET, 600 V, 4 A	4 ON Semiconductor		FDD4N60N
RGATE1 ~ 3, RA1 ~ 4	RES, SMD, 1/2 W, 3216	30	Yageo	0 Ω
RFF1 ~ RFF3		3		Open

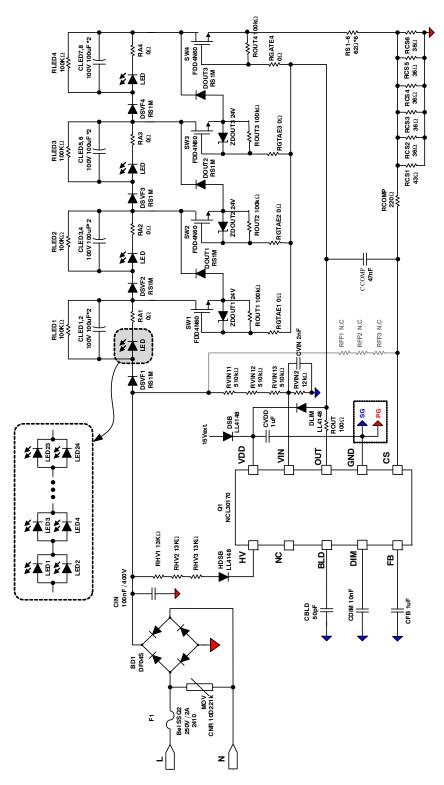


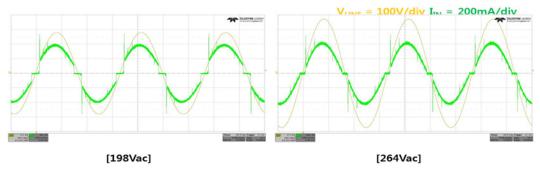
Figure 2. Schematic for High Line 60 W ADIM

Table 3. BILL OF MATERIALS FOR HIGH LINE (BOM)

Part Reference	Part Description	Q'ty	Vendor	Value
Q1	NCL30170 / IC SOIC 10	C SOIC 10 1		NCL30170
F1	2 A, 250 Vac MF2410F2.000TM	1	AEM	SMD
MOV	STF 10D391K	1		10φ
RCS1	RES, SMD, 1/2 W, 3216	1	Yageo	43 Ω
RCS2 ~ RCS6	RES, SMD, 1/2 W, 3216	5	Yageo	36 Ω
RHV1, RHV2, RHV3	RES, SMD, 1/2 W, 3216	3	Yageo	13 KΩ
RVIN11, RVIN12, RVIN13	RES, SMD, 1/2 W, 3216	3	Yageo	510 KΩ
RVIN2	RES, SMD, 1/2 W, 3216	1	Yageo	12 KΩ
RLED1 ~ RLED4, ROUT1 ~ ROUT4	RES, SMD, 1/2 W, 3216	8	Yageo	100 ΚΩ
ROUT	RES, SMD, 1/2 W, 3216	1	Yageo	100 Ω
RCOMP	RES, SMD, 1/2 W, 3216	1	Yageo	220 Ω
RS1 ~ RS6	RES, SMD, 1/2 W, 3216	6	Yageo	62 Ω
CVIN	100 nF / 600 V	/ 600 V 1		100 nF
CLED1 ~ CLED8	100 μF / 100 V	8	Samwha	100 μF
CVDD	Cap, 3216 SMD, Ceramic, 50 V, X7R	1	Kemet	1 μF
CBLD	Cap, 2012 SMD, Ceramic, 25 V, X7R	1 Kemet		50 pF
CDIM	Cap, 2012 SMD, Ceramic, 25 V, X7R	1 Kemet		10 nF
CFB	Cap, 2012 SMD, Ceramic, 25 V, X7R	X7R 1 Kemet		1 μF
CCOMP	Cap, 3216 SMD, Ceramic, 50 V, X7R	V, X7R 1 Kemet		47 nF
CVIN2	Cap, 3216 SMD, Ceramic, 50 V, X7R	1	Kemet	2 nF
DLIM	Diode, 100 V, 150 mA, Fast recovery	/, 150 mA, Fast recovery 1 ON Semiconductor		LL4148
DSVF1 ~ DSVF4, DOUT1 ~ DOUT3	Diode, 1000 V, 1 A, Fast recovery 7 ON Semiconductor		RS1M	
DSB, HDSB	Diode, 100 V, 150 mA, Fast recovery	0 V, 150 mA, Fast recovery 2 ON Semiconductor		LL4148
ZDOUT1, ZDOUT2, ZDOUT3	ZENER Diode, 24 V	3 ON Semiconductor		24 V
BD1	Bridge Diode 400 V, 1 A 1 ON Semiconductor		ON Semiconductor	DF04S
LED1 ~ LED96	MP-3030-2100-30-80 96		LUMINUS	6 V / 240 m/
SW1, SW2, SW3, SW4	MOSFET, 600 V, 4 A 4 ON Se		ON Semiconductor	FDD4N60N
RGATE1 ~ 4, RA1 ~ 4	RES, SMD, 1/2 W, 3216	30	Yageo	0 Ω
RFF1 ~ 3		5		Open

PERFORMANCE

Test Data – Analog Dimming Mode





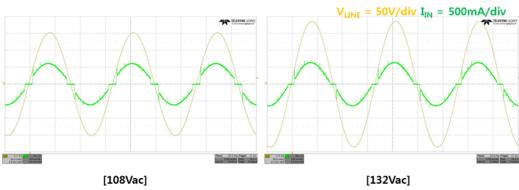
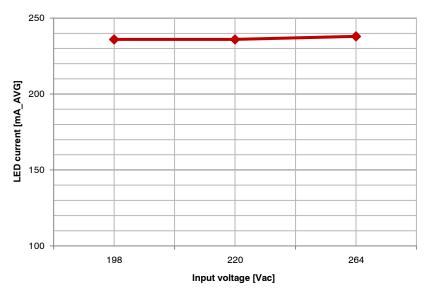


Figure 4. Normal	Operation for	or Low Line ADIM
rigare 4. Roman	operation	

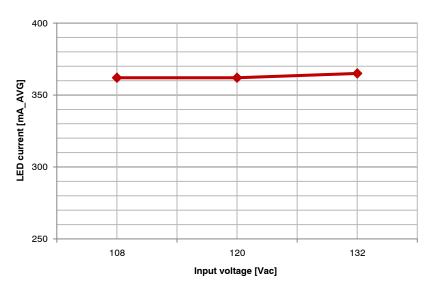
60 W High Line EVB			50 W Low Line EVB				
Input Voltage [Vac]	Input Power [W]	PF	THD [%]	Input Voltage [Vac]	Input Power [W]	PF	THD [%]
198	56.41	0.991	12.967	108	45.523	0.991	11.162
230	64.01	992	10.336	120	50.727	0.992	9.737
264	74.5	0.992	9.638	132	56.032	0.992	9.654

High line 60W ADIM



Average LED current

Figure 5. Line Regulation Performance for High Line (ADIM)

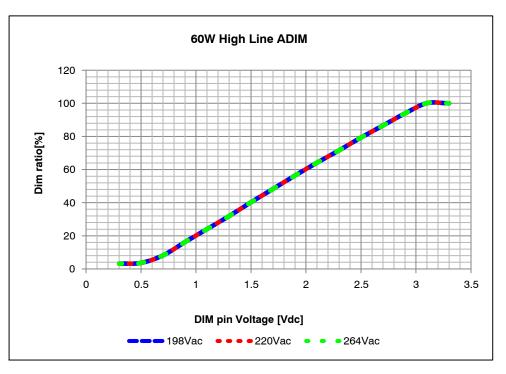


Low line 50W ADIM

Average LED current

Figure 6. Line Regulation Performance for Low Line (ADIM)

Dimming Performance



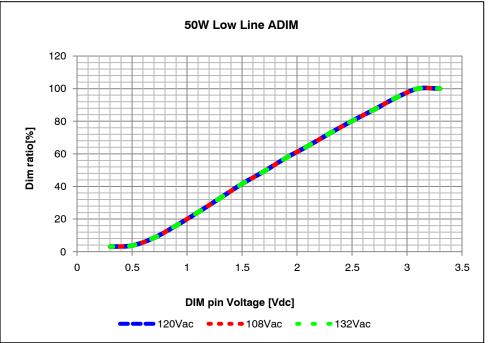
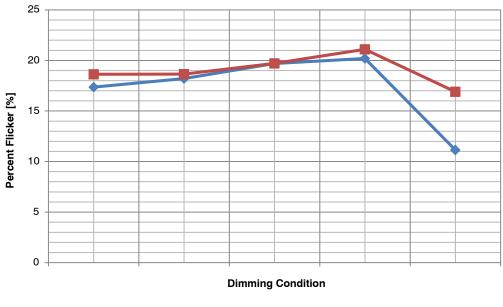


Figure 7. Dimming Curve for Analog Dimming

Percent Flicker with Electrolytic Capacitor

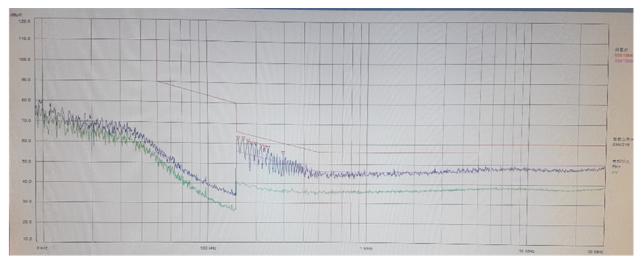
Percent Flicker for 60 W / 50 W ADIM EVB



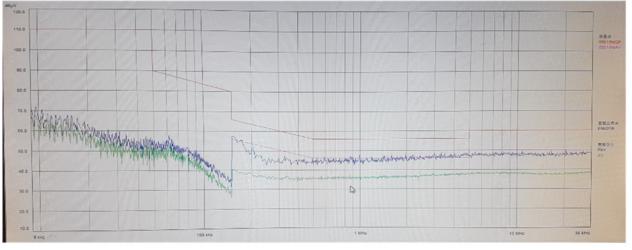
High Line 60 W – Low Line 50 W

Figure 8. Percent Flicker Performance

Conducted EMI



[60W High Line ADIM]



[50W Low Line ADIM]



Surge Test

Test condition: Boards mounted to 25 cm x 18 cm x 4.5 cm heatsink Heatsink connected to Earth ground DM: Differential Mode test applies surge between Line and Neutral CM: Common Mode test applies surge between Line + Neutral connected and Earth ground Combination wave: 3 strikes

Table 5. TEST RESULT FOR COMBINATION WAVE

Test EVB	Test Result	Surge Immunity Component	
60 W High Line	±2 kV passed	MOV 10D221K (10pi)	
50 W Low Line	±2 kV passed	MOV 10D391K (10pi)	

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